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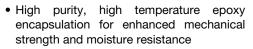
High Performance Schottky Rectifier, 16 A



PRIMARY CHARACTERISTICS				
I _{F(AV)}	16 A			
V_{R}	35 V, 45 V			
V _F at I _F	0.57 V			
I _{RM} max.	40 mA at 125 °C			
T _J max.	150 °C			
E _{AS}	24 mJ			
Package	2L TO-220AC			
Circuit configuration	Single			

FEATURES

- 150 °C T_J operation
- Low forward voltage drop
- · High frequency operation





- Guard ring for enhanced ruggedness and long term reliability
- Designed and qualified according to JEDEC®-JESD 47
- Material categorization: for definitions of compliance please see <u>www.vishay.com/doc?99912</u>

DESCRIPTION

The VS-MBR16... Schottky rectifier has been optimized for low reverse leakage at high temperature. The proprietary barrier technology allows for reliable operation up to 150 °C junction temperature. Typical applications are in switching power supplies, converters, freewheeling diodes, and reverse battery protection.

MAJOR RATINGS AND CHARACTERISTICS				
SYMBOL	CHARACTERISTICS	VALUES	UNITS	
I _{F(AV)}	Rectangular waveform	16	Α	
V_{RRM}		35, 45	V	
I _{FSM}	t _p = 5 μs sine	1800	Α	
V _F	16 A _{pk} , T _J = 125 °C	0.57	V	
T_J	Range	-65 to +150	°C	

VOLTAGE RATINGS				
PARAMETER	SYMBOL	VS-MBR1635-M3	VS-MBR1645-M3	UNITS
Maximum DC reverse voltage	V_R	35	45	V
Maximum working peak reverse voltage	V_{RWM}	33	45	V

ABSOLUTE MAXIMUM RATINGS					
PARAMETER	SYMBOL	TEST CONDITIONS		VALUES	UNITS
Maximum average forward current	I _{F(AV)}	T_C = 134 °C, rated V_R		16	Α
Non-repetitive peak surge current	I _{ESM}	5 μs sine or 3 μs rect. pulse	Following any rated load condition and with rated V _{RRM} applied	1800	А
		Surge applied at rated load of single phase, 60 Hz	condition half wave	150	
Non-repetitive avalanche energy	E _{AS}	$T_J = 25 ^{\circ}\text{C}, I_{AS} = 3.6 \text{A}, L = 3.7 \text{mH}$		24	mJ
Repetitive avalanche current	I _{AR}	Current decaying linearly to zero in 1 μ s Frequency limited by T_J maximum $V_A = 1.5 \times V_R$ typical 3.6		А	



VS-MBR1635-M3, VS-MBR1645-M3

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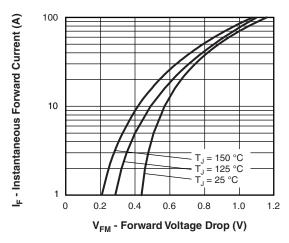
ELECTRICAL SPECIFICATIONS					
PARAMETER	SYMBOL	TEST CONDITIONS		VALUES	UNITS
Maximum forward voltage drop	V _{FM} ⁽¹⁾	16 A	T _J = 25 °C	0.63	V
waxiinum lorward voitage drop	V FM (1)	10 A	T _J = 125 °C	0.57] v
Mariana	I _{RM} ⁽¹⁾	T _J = 25 °C	Rated DC voltage	0.2	mA
Maximum instantaneous reverse current I _{RM} (1)		T _J = 125 °C	nated DC voltage	40	IIIA
Maximum junction capacitance	C _T	V _R = 5 V _{DC} (test signal range 100 kHz to 1 MHz) 25 °C 1400 pF		pF	
Typical series inductance	L _S	Measured from top of terminal to mounting plane 8.0		nH	
Maximum voltage rate of change	dV/dt	Rated V _R 10 000 V/ _k		V/µs	

Note

 $^{^{(1)}\,}$ Pulse width < 300 µs, duty cycle < 2 %

THERMAL - MECHANICAL SPECIFICATIONS				
PARAMETER	SYMBOL	TEST CONDITIONS	VALUES	UNITS
Maximum junction temperature range	TJ		-65 to +150	°C
Maximum storage temperature range	T _{Stg}		-65 to +175	
Maximum thermal resistance, junction to case	R _{thJC}	DC operation	1.50	°C/W
Typical thermal resistance, case to heatsink	R _{thCS}	Mounting surface, smooth and greased	0.50	C/VV
Approximate weight			2	g
Approximate weight			0.07	OZ.
Mauratic vi tarania minimum			6 (5)	kgf ⋅ cm
Mounting torque — maximum			12 (10)	(lbf \cdot in)
Morting device		Coop atula 21, TO 220AC (IEDEC)	MBR1635	
Marking device		Case style 2L TO-220AC (JEDEC)	MBR1645	

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100 T₁ = 150 °C I_R - Reverse Current (µA) 10 $T_{J} = 125$ T₁ = 100 °C 0.1 T_J = 75 °C _ = 50 °C 0.01 = 25 °C 0.001 0.0001 0 5 25 30 40 15 20 V_R - Reverse Voltage (V)

Fig. 1 - Maximum Forward Voltage Drop Characteristics

Fig. 2 - Typical Values of Reverse Current vs. Reverse Voltage

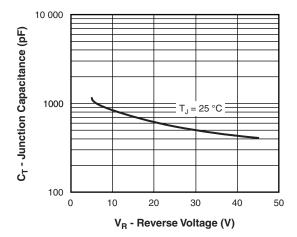


Fig. 3 - Typical Junction Capacitance vs. Reverse Voltage

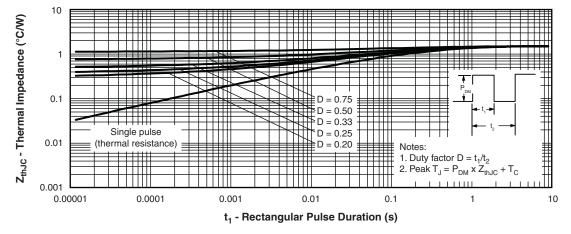


Fig. 4 - Maximum Thermal Impedance Z_{thJC} Characteristics



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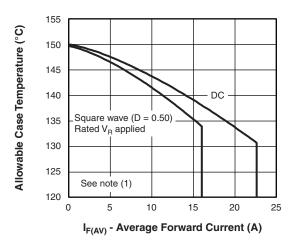


Fig. 5 - Maximum Allowable Case Temperature vs. Average Forward Current

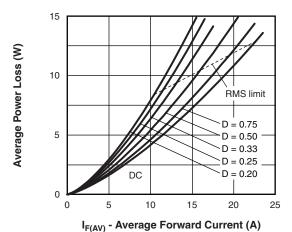


Fig. 6 - Forward Power Loss Characteristics

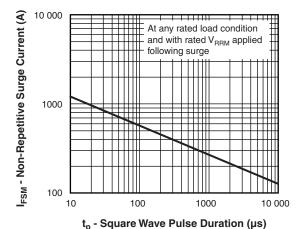


Fig. 7 - Maximum Non-Repetitive Surge Current (Per Leg)

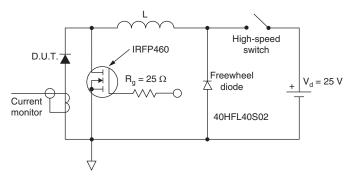


Fig. 8 - Unclamped Inductive Test Circuit

Note

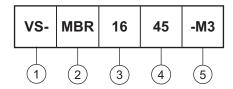
 $\begin{array}{ll} \text{(1)} & \text{Formula used: } T_C = T_J - (Pd + Pd_{REV}) \times R_{thJC}; \\ Pd = \text{forward power loss} = I_{F(AV)} \times V_{FM} \text{ at } (I_{F(AV)}/D) \text{ (see fig. 6)}; \\ Pd_{REV} = \text{inverse power loss} = V_{R1} \times I_R \text{ (1 - D); } I_R \text{ at } V_{R1} = \text{rated } V_R \text{ applied} \end{array}$

VS-MBR1635-M3, VS-MBR1645-M3

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ORDERING INFORMATION TABLE

Device code



Vishay Semiconductors product

2 - Schottky MBR series

Current rating (16 = 16 A)

- Voltage ratings — 35 = 35 V 45 = 45 V

5 - Environmental digit

-M3 = halogen-free, RoHS-compliant, and termination lead (Pb)-free

ORDERING INFORMATION (Example)				
PREFERRED P/N	QUANTITY PER T/R	MINIMUM ORDER QUANTITY	PACKAGING DESCRIPTION	
VS-MBR1635-M3	50	1000	Antistatic plastic tube	
VS-MBR1645-M3	50	1000	Antistatic plastic tube	

LINKS TO RELATED DOCUMENTS			
Dimensions <u>www.vishay.com/doc?96156</u>			
Part marking information	www.vishay.com/doc?95391		



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